NSN 5961-01-150-3638

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Inclosure Material:
Metal
Overall Length:
1.330 inches
Overall Diameter:
Between 0.570 inches and 0.610 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact-darlington connected
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-61
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.667 inches and 0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
425.0 collector to emitter voltage/static/base open and 500.0 collector to base voltage/static/emitter open and 8.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
20.00 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
82577-h980022 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a

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Unit Of Measure:

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